

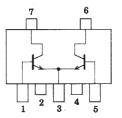
FP201

NPN Epitaxial Planar Silicon Composite Transistors
High-Frequency Amp,
Differential Amp Applications

Features

- · Composite type with 2 transistors contained in the PCP package currently in use, improving the mounting efficiency greatly.
- The FP201 is formed with two chips, being equivalent to the 2SC4504, placed in one package.
- · Excellent in thermal equilibrium and pair capability.

Electrical Connection

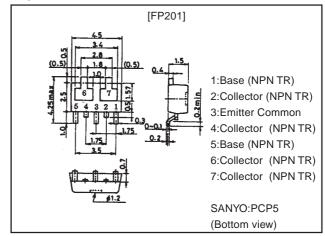


1:Base (NPN TR)
2:Collector (NPN TR)
3:Emitter Common
4:Collector (NPN TR)
5:Base (NPN TR)
6:Collector (NPN TR)
7:Collector (NPN TR)
(Top view)

Package Dimensions

unit:mm

2107A



Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|--|-------------|------|
| Collector-to-Base Voltage | V _{CBO} | | 30 | V |
| Collector-to-Emitter Voltage | VCEO | | 20 | V |
| Emitter-to-Base Voltage | V _{EBO} | | 3 | V |
| Collector Current | lc | | 300 | mA |
| Collector Current (Pulse) | I _{CP} | | 600 | mA |
| Collector Dissipation | PC | Mounted on ceramic board (250mm ² ×0.8mm) 1unit | 0.75 | W |
| Total Dissipation | PT | Mounted on ceramic board (250mm ² ×0.8mm) | 1.0 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

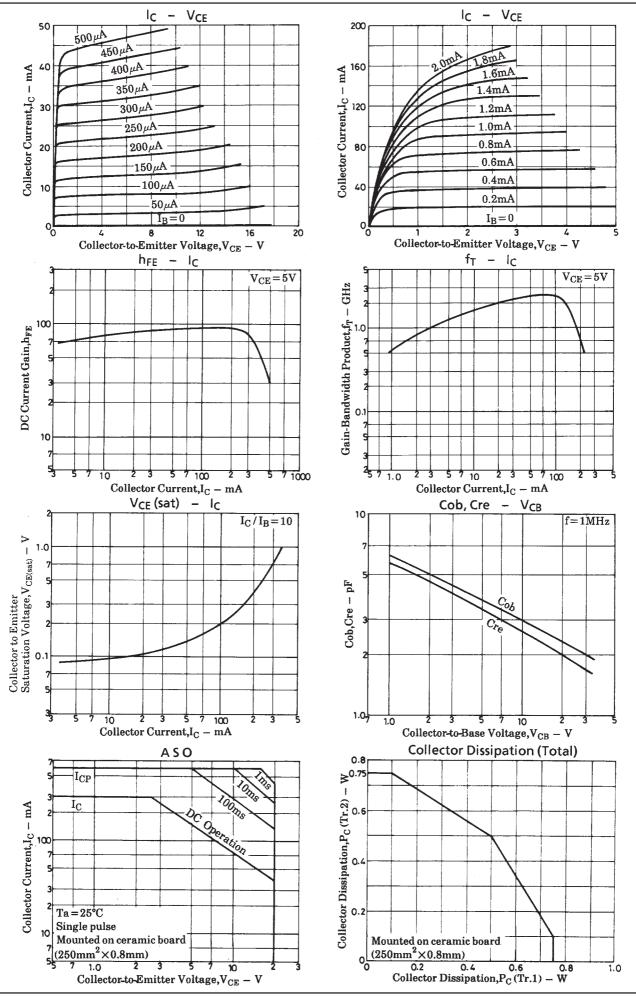
Electrical Characteristics at Ta=25°C

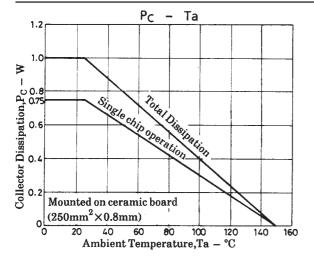
| Parameter | Symbol | Conditons | | Ratings | | |
|------------------------------------|-------------------------------------|---|-----|---------|-----|------|
| | Symbol | | min | typ | max | Unit |
| Collector Cutoff Current | I _{CBO} | V _{CB} =20V, I _E =0 | | | 1.0 | μA |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =2V, I _C =0 | | | 5.0 | μA |
| DC Current Gain | h _{FE} 1 | V _{CE} =5V, I _C =50mA | 60 | | 200 | |
| | h _{FE} 2 | V _{CE} =5V, I _C =300mA | 20 | | | |
| DC Current Gain Ratio | h _{FE} 1(smal- l/large) | V _{CE} =5V, I _C =50mA | 0.7 | 0.95 | | |
| Base-to-Emitter Voltage Difference | V _{BE} (large- small | V _{CE} =5V, I _C =100mA | | 3.0 | 15 | mV |
| Gain-Bandwidth Product | fT | V _{CE} =5V, I _C =50mA | | 2.2 | | GHz |
| Output Capacitance | Cob | V _{CB} =10V, f=1MHz | | 2.9 | | pF |
| Reverse Transfer Capacitance | Cre | V _{CB} =10V, f=1MHz | | 2.6 | | pF |
| C-E Saturation Voltage | V _{CE(sat)} | I _C =200mA, I _B =20mA | | 0.2 | 0.5 | V |
| B-E Saturation Voltage | V _{BE(sat)} | I _C =200mA, I _B =20mA | | 0.9 | 1.2 | V |

Note: The specifications shown above are for each individual transistor.

However, the DC Current Gain Ratio and Base Emitter to Voltage Difference are for the paired transistors.

Marking:201





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